

PUMH20

50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = 2.2 k Ω

16 May 2023

Product data sheet

1. General description

NPN/NPN double Resistor-Equipped Transistor (RET) in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

NPN/PNP complement: PUMD20 PNP/PNP complement: PUMB20

2. Features and benefits

- Built-in bias resistors
- Simplifies circuit design
- · Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

3. Applications

- Low current peripheral driver
- · Control of IC inputs
- Replacement of general-purpose transistors in digital applications

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor	Per transistor						
V _{CEO}	collector-emitter voltage	open base		-	-	50	V
Io	output current			-	-	100	mA
R1	bias resistor 1 (input)			1.54	2.2	2.86	kΩ
R2/R1	bias resistor ratio			0.8	1	1.2	



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		O1 I2 GND2
2	I1	input (base) TR1		
3	O2	output (collector) TR2	6 5 4	R1 R2
4	GND2	GND (emitter) TR2		TR2
5	12	input (base) TR2		TR1 R2 R1
6	01	output (collector) TR1	☐1 ☐2 ☐3 TSSOP6 (SOT363)	GND1 I1 O2 aaa-019894

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PUMH20		plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	<u>SOT363</u>

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PUMH20	н7%

[1] % = placeholder for manufacturing site code

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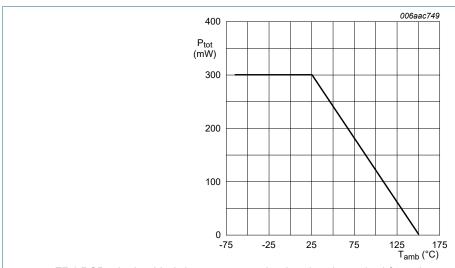
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transisto	or					
V _{CBO}	collector-base voltage	open emitter		-	50	V
V _{CEO}	collector-emitter voltage	open base		-	50	V
V _{EBO}	emitter-base voltage	open collector		-	10	V
VI	input voltage			-10	12	V
Io	output current			-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	200	mW
Per device			•			
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	300	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



FR4 PCB, single-sided, 35 μm copper, tin-plated and standard footprint

Fig. 1. Per device: Power derating curve

50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = 2.2 k Ω

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	416	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

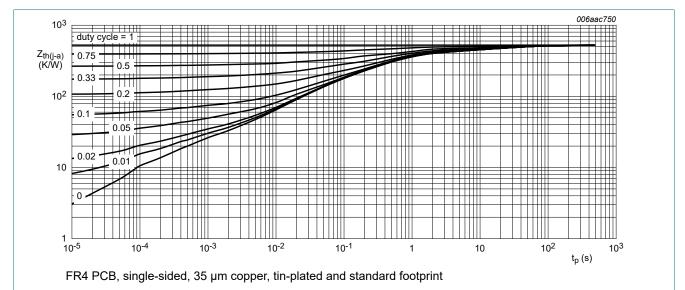


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = 2.2 k Ω

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transist	or					
V _{(BR)CBO}	collector-base breakdown voltage	$I_C = 100 \mu A; I_E = 0 A; T_{amb} = 25 °C$	50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	50	-	-	V
I _{CBO}	collector-base cut-off current	V _{CB} = 50 V; I _E = 0 A; T _{amb} = 25 °C	-	-	100	nA
I _{CEO}	collector-emitter cut-off	V _{CE} = 30 V; I _B = 0 A; T _{amb} = 25 °C	-	-	100	nA
	current	V _{CE} = 30 V; I _B = 0 A; T _j = 150 °C	-	-	5	μA
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C	-	-	2	mA
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 20 mA; T _{amb} = 25 °C	30	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}; T_{amb} = 25 \text{ °C}$	-	-	150	mV
V _{I(off)}	off-state input voltage	V _{CE} = 5 V; I _C = 1 mA; T _{amb} = 25 °C	-	1.2	0.5	V
V _{I(on)}	on-state input voltage	V _{CE} = 0.3 V; I _C = 20 mA; T _{amb} = 25 °C	2	1.6	-	V
R1	bias resistor 1 (input)		1.54	2.2	2.86	kΩ
R2/R1	bias resistor ratio		0.8	1	1.2	
C _c	collector capacitance	V _{CB} = 10 V; I _E = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	-	2.5	pF

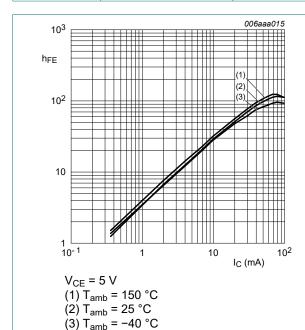


Fig. 3. DC current gain as a function of collector current; typical values

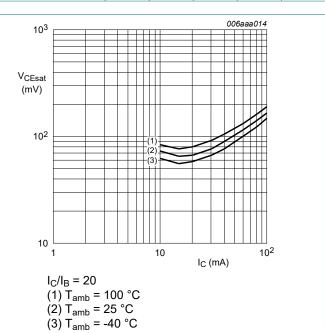
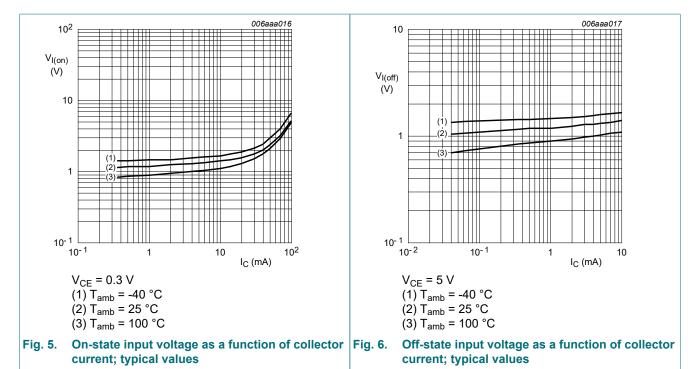


Fig. 4. Collector-emitter saturation voltage as a function of collector current; typical values

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50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = 2.2 k Ω

11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

Resistor calculation

• Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{2}) - V(I_{1})}{I_{2} - I_{1}}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I4) - V(I3)}{R1 \cdot (I4 - I3)} - 1$$

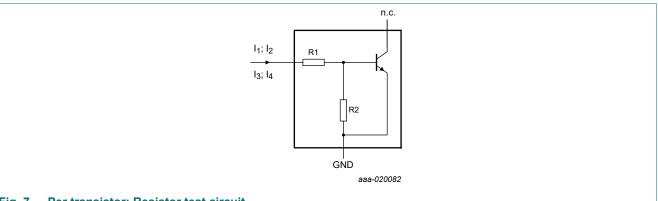


Fig. 7. Per transistor: Resistor test circuit

Resistor test conditions

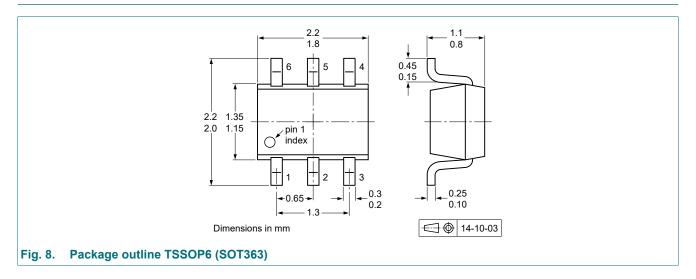
Table 8. Resistor test conditions

7	Type number	R1 (kΩ)	R2 (kΩ)	Test conditions			
				I ₁	l ₂	l ₃	14
F	PUMH20	2.2	2.2	750 µA	950 µA	-750 µA	-950 μA

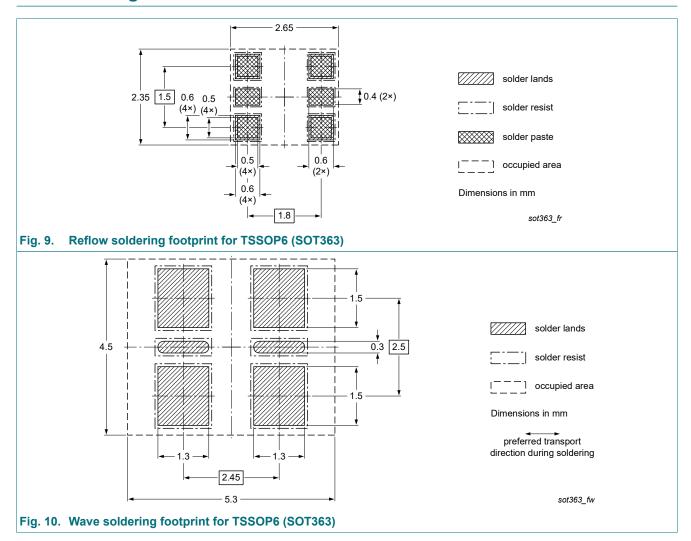
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50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = 2.2 k Ω

12. Package outline



13. Soldering



50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 2.2 k Ω , R2 = 2.2 k Ω

14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PUMH20 v.5	20230516	Product data sheet	-	PEMH20_PUMH20_4
Modifications:	guidelines of l Legal texts ha Family data s	Nexperia.	the new com	ned to comply with the identity spany name where appropriate. sheet.
PEMH20_PUMH20_4	20091115	Product data sheet	-	PEMH20_PUMH20_3
PEMH20_PUMH20_3	20050214	Product data sheet	-	PUMH20_2
PUMH20_2	20040414	Product specification	-	PUMH20_1
PUMH20_1	20031016	Product specification	-	-

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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